NSN 5961-01-357-1126

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-357-1126 **Inclosure Material:** Metal and ceramic **Overall Length:** 0.025 inches **Overall Width:** 0.025 inches **Mounting Method:** Press fit **Features Provided:** Burn in **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.845 regulator voltage and 5.355 regulator voltage **Current Rating Per Characteristic:** 55.00 milliamperes source cutoff current horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Nuclear hardness critical item **Terminal Type And Quantity:** 1 bonding pad and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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